
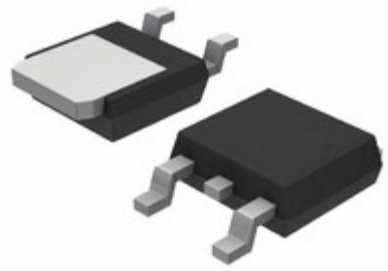
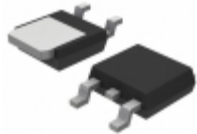
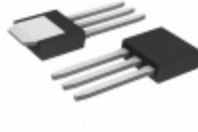





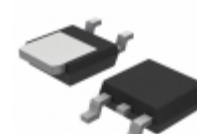
	<h2>NTD2955PT4G</h2>
	<p>Hersteller-Teilenummer: NTD2955PT4G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 60V 12A DPAK</p> <p>Datenblätter:  NTD2955PT4G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 10000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD2955PT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 60V 12A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	10000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK-3
Verlustleistung (max)	55W (Tj)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Ta)
Rds On (Max) @ Id, Vgs	180 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	750pF @ 25V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 <p>NTD2955T4G AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 12A DPAK</p>	 <p>NTD2955-1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 12A IPAk</p>	 <p>NTD2955-1 AMI Semiconductor / ON Semiconductor NTD2955-1 ON</p>	 <p>NTD2955VT4G O NTD2955VT4G O</p>
 <p>NTD2955T4 ON NTD2955T4 ON</p>	 <p>NTD2955D O NTD2955D O</p>	 <p>NTD2955V ON NTD2955V ON</p>	 <p>NTD2955G AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 12A DPAK</p>

heiße Teile

Mehr

 NTD24N06G	 NTD24N06L	 NTD24N06L-001	 NTD24N06L-1G	 NTD24N06L4T
 NTD24N06LG	 NTD24N06LT4	 NTD24N06LT4G	 NTD24N06T4	 NTD24N06T4G
 NTD25N06HL	 NTD25P03	 NTD25P03L	 NTD25P03L-1	 NTD25P03L1G
 NTD25P03LG	 NTD25P03LRLG	 NTD25P03LT4G	 NTD25P06LT4G	 NTD2955-001
 NTD2955-1	 NTD2955-1G	 NTD2955D	 NTD2955E	 NTD2955G
 NTD2955T4	 NTD2955T4G	 NTD2955V	 NTD2955VT4G	 NTD3055-094
 NTD3055-094-1G	 NTD3055-094G	 NTD3055-094T4	 NTD3055-094T4G	 NTD3055-150
 NTD3055-150-1G	 NTD3055-150G	 NTD3055-150T4	 NTD3055-150T4G	 NTD3055-170T4G
 NTD3055L104T4G	 NTD3055L	 NTD3055L04T4G	 NTD3055L104	 NTD3055L104-1G
 NTD3055L104G	 NTD3055L104T4G	 NTD3055L170	 NTD3055L170-001	 NTD3055L170-1G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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